

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF

MASAYUKI TANAKA, ET AL. : EXAMINER: DANG, PHUC T

SERIAL NO: 10/717,719 :

FILED: NOVEMBER 21, 2003 : GROUP ART UNIT: 2818

FOR: A NONVOLATILE

SEMICONDUCTOR MEMORY AND MANUFACTURING METHOD FOR THE

SAME

AMENDMENT UNDER EX PARTE QUAYLE

COMMISSIONER FOR PATENTS ALEXANDRIA, VIRGINIA 22313

SIR:

In response to the Office Action dated January 19, 2005, please amend the aboveidentified application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 3 of this paper.

Remarks/Arguments begin on page 10 of this paper.